

BOA1060080YY120MXXXX

Fiber Coupled Booster Semiconductor Optical Amplifier



Features:

- High output power (120mW) @ 1060nm
- High saturation output power (19dBm)
- Low ripples
- Strong linear polarization
- RoHS compliance
- Proprietary anti-reflection coating technology enabling high reliability
- Polarization maintaining PM980 fiber or HI1060 fiber
- 900um loose tube on fiber (optional)

Applications:

- Swept-source, tunable lasers
- Optical preamplifiers
- Optical coherence tomography (OCT)

Recommended Operating Conditions

@ CW, the case is mounted on 25°C heatsink

Parameter	Min.	Typ.	Max.	Unit
Chip Temperature	20	25	30	°C
Forward Current		400	500	mA
Output Power in Amplification Mode			120	mW
Input Optical Power	-25	10	15	dBm

Gain Characteristics

@ CW, 25°C, 400mA, with input signal 10dBm, 1060nm

Parameter	Min.	Typ.	Max.	Unit
Forward Current @ 120mW			500	mA
Small Signal Gain @ Pin=-25dBm	12	15		dB
Saturation Output Power @ -3dB	16	19		dBm
Mean Wavelength	1040	1060	1080	nm
Bandwidth @ -3dB		80		nm

Amplified Spontaneous Emission (ASE) Characteristics

@ CW, 25°C, 400mA, no input signal

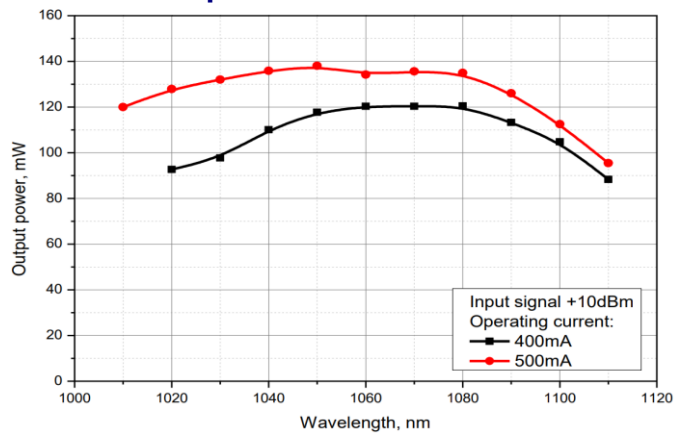
Parameter	Min.	Typ.	Max.	Unit
Output Power (each port)		1		mW
Forward Voltage		1.7	2.1	V
Mean Wavelength		1015		nm
Bandwidth (FWHM)		25		nm
Ripples* (RMS)		0.01	0.1	dB
Polarisation Extinction Ratio (PER)	15	18		dB
Polarization		TE		

* - measured in 1nm span around spectrum maximum with 20pm resolution.

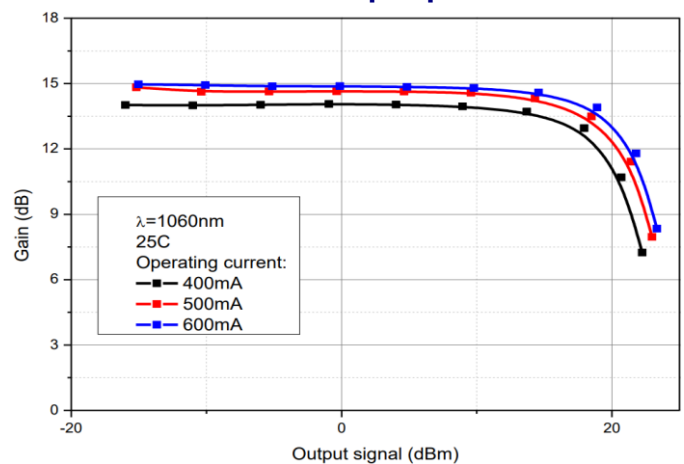
Typical Performance (for reference only)

@ CW, the case is mounted on 25°C heatsink

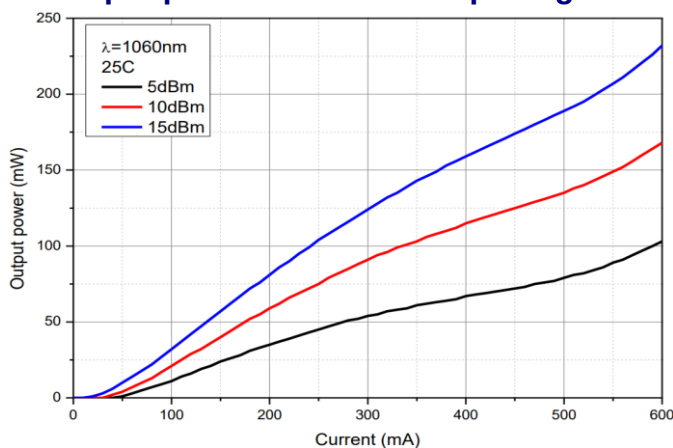
Power spectra at different currents



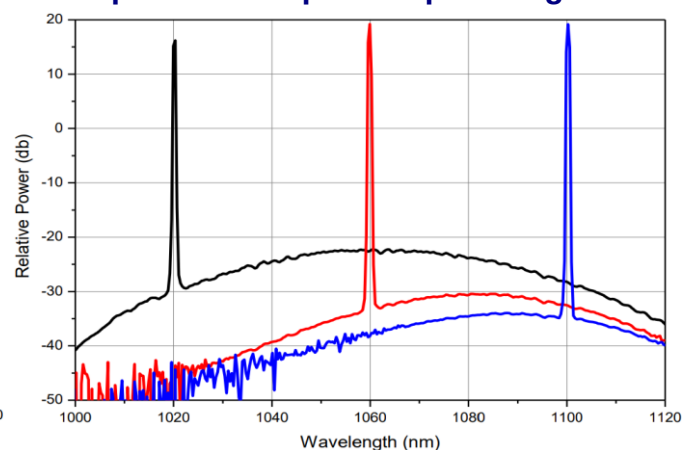
Gain vs. Output power



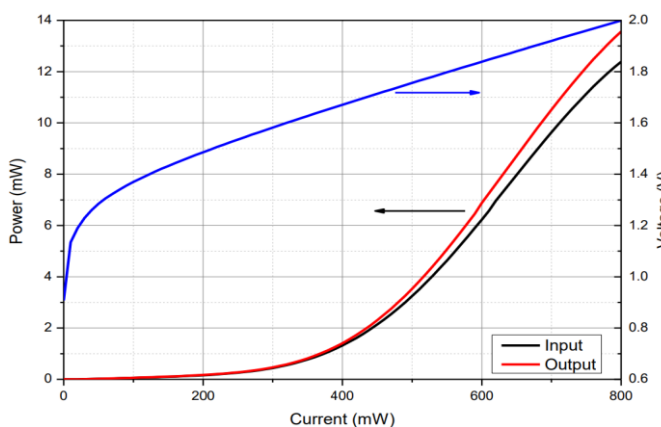
Output power at different input signals



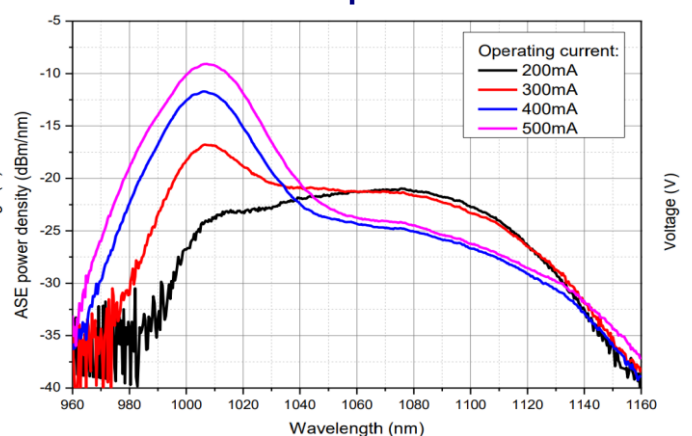
Spectra of amplified optical signal



ASE LIV characteristics



ASE spectra

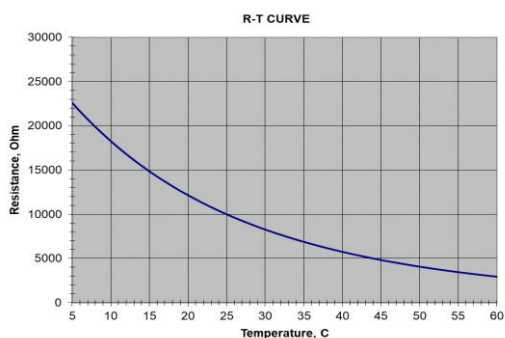


Absolute Maximum Ratings

Parameter	Min	Max	Unit
Output Optical Power		300	mW
Input Optical Power		20	dBm
Forward Current		600	mA
Reverse Voltage		2	V
TEC Current		3	A
TEC Voltage		4	V
Chip Operating Temperature	10	40	°C
Case Operating Temperature	0	70	°C
Storage Temperature	-40	85	°C
Pin Soldering Temperature (max 10 sec, max case temperature 120°C)		300	°C
Fiber Band Radius	3		cm

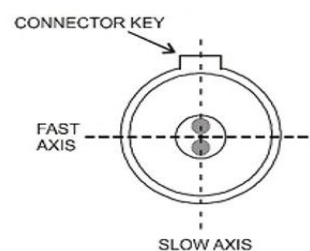
Thermistor specification

Parameters	Value	Unit
Type	NTC	
Resistance @ 25°C	10±0.1	kOhm
Beta 25-85°C	3435±1%	K



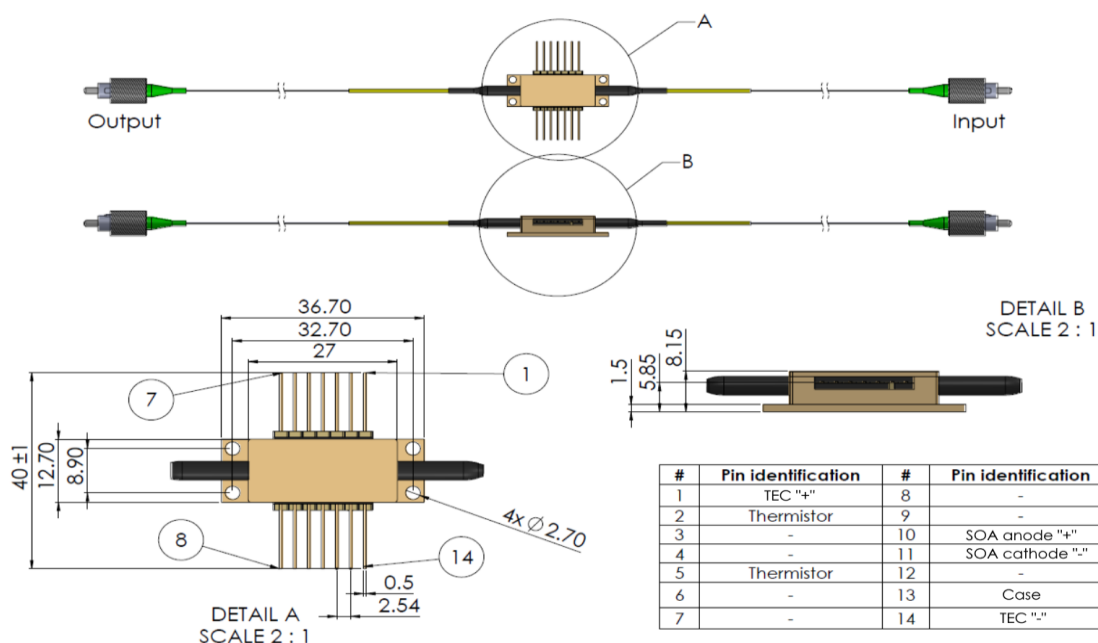
Fiber specification

Parameters	Value	Value	Unit
Fiber Type	HI1060	PM980	
Numerical Aperture (Typical)	0.14	0.12	
Cut-off Wavelength	920±50	900±70	nm
Mode-Field Diameter	6.2±0.3 @1060nm	6.6±0.3 @1060nm	µm
Cladding Diameter	125±1	125±1	µm
Coating Diameter	245±15	245±15	µm
Loose Tube Diameter (optional)	900	900	µm
Connector	FC/APC	FC/APC	
Key	narrow	narrow	



The output light is polarized along the slow axis of PM fiber.

Dimensions (in mm)



Safety and Operating Instructions

The light emitted from this device is invisible and can be harmful to the human eye. Avoid looking directly into the fiber connector when the device is in operation. Proper laser safety eyewear must be worn during operation with open connector.

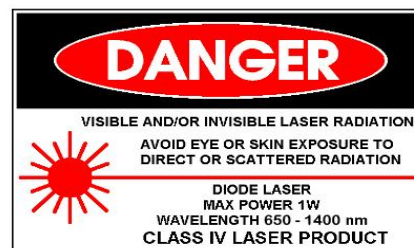
Absolute Maximum Ratings may be applied to the device for short period of time only. Exposure to maximum ratings for extended period of time or exposure to more than one maximum rating may cause damage or affect the reliability of the device. Operating the device outside of its maximum ratings may cause device failure or a safety hazard. Power supplies used with the component must be employed such that the maximum forward current cannot be exceeded.

A proper heatsink for the device on thermal radiator is required. The device must be mounted on radiator with 4 screws (bolt down in X-style fashion with initial torque set to 0.075Nm and final X-style bolt down at 0.15Nm) or with clamps. The deviation from flatness of radiator surface must be less than 0.05mm. It's recommended using of Indium foil or thermal conductive and soft material between bottom of the case and heatsink for thermal interface. It's undesirable to use thermal grease for this.

Avoid back reflection to the device. It may give impact on the device performance in aspects of spectrum and power stability. It also may cause fatal facet damage. Using of optical isolators is highly recommended to block back reflection.

Do not pull the fiber. Do not bend a fiber with a radius smaller than 3 cm. Fiber tip should always be protected from any contamination or damage during the process of installation. After removing the dust-preventing cap covered at fiber tip, carefully clean fiber tip by wiping through one direction using optical lens cleaning paper or cotton swab dabbed with Iso-Propanol or Ethyl alcohol. Operate the device with clean fiber connector only.

ESD PROTECTION - Electrostatic discharge is the primary cause of unexpected product failure. Take extreme precaution to prevent ESD. During device installation, ESD protection has to be maintained - use wrist straps, grounded work surfaces and rigorous antistatic techniques when handling the product.



Part-number Identification

BOA1060080HI120MXXXX -> 120mW output power at 1060nm mean wavelength, 80nm bandwidth, HI-1060 fiber
BOA1060080PM120MLXXX -> 120mW output power at 1060nm mean wavelength, 80nm bandwidth, PM-980 fiber, with loose tube

NOTE: Innolume product specifications are subject to change without notice